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Influence of Nb-doped TiO₂ blocking layers as a cascading band structure

for enhanced photovoltaic properties

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Highlights

▶ Nb-doped TiO₂ (Nb-TiO₂) layers prepared by using horizontal ultrasonic spray pyrolysis

deposition.

▶ Nb-TiO₂ layers formed a cascading band structure to efficiently suppress the electron

recombination.

► Nb-TiO₂ layers resulted in the increase of the electrical conductivity by the Nb doping into TiO₂.

▶ A novel blocking layer for improving the photovoltaic performances of dye-sensitized solar cells.

Abstract

Nb-doped TiO₂ (Nb-TiO₂) blocking layers (BLs) were developed using horizontal ultrasonic spray pyrolysis deposition (HUSPD). In order to improve the photovoltaic properties of the dye-sensitized solar cells (DSSCs), we optimized the Nb doping level of the Nb-TiO₂ BLs by controlling the Nb/Ti molar ratio (0, 5, 6, and 7) of the precursor solution for

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